

BUV21G

BUV21G Information



Part Number	BUV21G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN 200V 40A TO-3
Package	TO-204AE
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BUV21G Specifications

Manufacturer Part Number	BUV21G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-204AE
Series	SWITCHMODE?
Transistor Type	NPN
Current - Collector (Ic) (Max)	40A
Voltage - Collector Emitter Breakdown (Max)	200V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 3A, 25A
Current - Collector Cutoff (Max)	3mA
DC Current Gain (hFE) (Min) @ Ic, Vce	20 @ 12A, 2V
Power - Max	250W
Frequency - Transition	8MHz
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-204AE
Supplier Device Package	TO-3
	Report errors?

BUV21G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about BUV21G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com